LM5007 75V、0.5A DC/DC降圧コンバータ、80VパワーMOSFET内蔵

1 特長

- 多用途な同期整流降圧DC/DCコンバータ
  - 動作入力電圧範囲:9V～75V
  - 80V、0.7AのNチャネル降圧スイッチを内蔵
  - 高電圧V_{CC}レギュレータを内蔵
  - 可変出力電圧
  - 高効率動作
- 適応型コンスタント・オンタイム制御アーキテクチャ
  - 超高速の過渡応答
  - 制御ループ補償が不要
- ほぼ一定のスイッチング周波数
  - PWMオン時間は入力電圧と反比例
- 高精度の2.5V基準電圧
- 低い入力静止電流
- 本質的な保護機能による堅牢な設計
  - インテリジェントな電流制限保護機能
  - VCCおよびゲート・ドライブのUVLO保護
  - ヒステリシス付きのサーマル・シャットダウン保護
  - 外部でのシャットダウン制御
- 8ピンVSSOPおよびWSONパッケージ
- WEBENCH® Power Designerを使用してカスタム・レギュレータ設計を作成

2 アプリケーション

- 非絶縁型DC/DC降圧レギュレータ
- 二次高圧ポスト・レギュレータ
- 48V車載システム

3 概要

LM5007 0.5A降圧スイッチング・コンバータには、低コストで高効率の降圧レギュレータを実装するために必要な、すべての機能が搭載されています。この高電圧コンバータには、80V、0.7AのNチャネル降圧スイッチが内蔵されており、9V～75Vの入力電圧範囲で動作します。実装が簡単で、8ピンVSSOPおよび熱的に強化された8ピンWSONパッケージで供給されます。

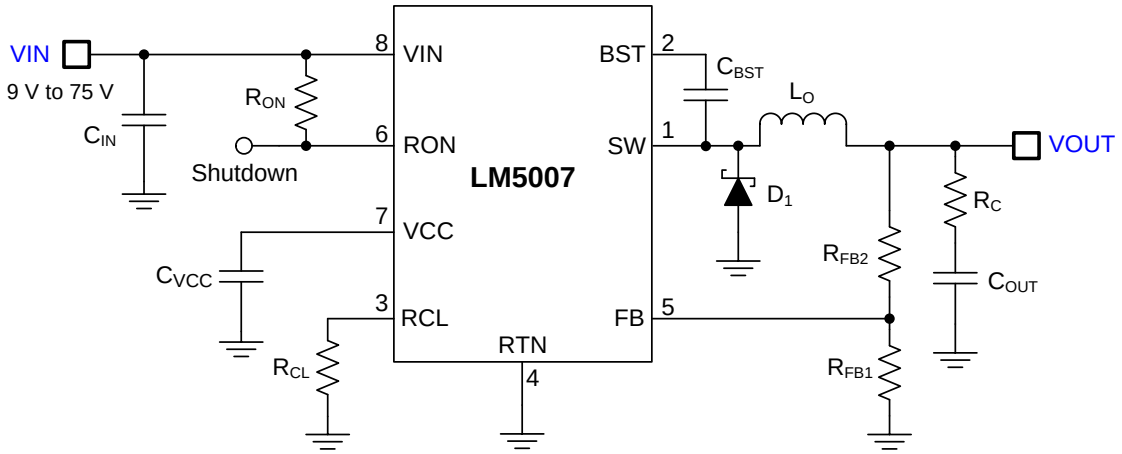
このコンバータは、PWMオン時間をV_{IN}に反比例させるヒステリシス制御方式を採用しています。この機能により、負荷および入力電圧が変化しても、動作周波数は比較的一定に維持されます。ヒステリシス制御はループ補償を必要としないため、高速な過渡応答が得られます。V_{OUT}に反比例する強制的オフ時間を持たせるインテリジェントな電流制限機能が実装されており、この電流制限方式により短絡保護を確実にし、負荷電流フォールドバックを減らすことができます。その他の保護機能として、自動回復機能付きサーマル・シャットダウン、V_{CC}およびゲート・ドライブの低電圧誤動作防止、最大デューティ・サイクル制限などがあります。

製品情報(1)

型番	パッケージ	本体サイズ(公称)
LM5007	VSSOP (8)	3.00mm×3.00mm
	WSON (8)	4.00mm×4.00mm

(1) 提供されているすべてのパッケージについては、巻末の注文情報を参照してください。

代表的なアプリケーションの回路図



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4 改訂履歴

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Revision G (October 2015) から **Revision H** に変更 **Page**

- *特長*、編集上 変更 ... 1
- *代表的なアプリケーションの回路図*、編集上 変更 ... 1
- Changed *Overcurrent Protection*, editorial ... 10
- Changed *Figure 7*, editorial ... 13
- Changed *Power Supply Recommendations*, editorial ... 17
- Changed *Layout Example* to specify recommended component placement ... 18
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Revision F (March 2013) から **Revision G** に変更 **Page**

- 「*製品情報*」表、「*ESD定格*」表、「*熱に関する情報*」表、「*アプリケーション情報*」セクション、「*設計要件*」セクション、「*アプリケーション曲線*」セクション、「*電源に関する推奨事項*」セクション、「*レイアウト*」セクション、「*コミュニティ・リソース*」セクションを追加 .. 1
- *代表的なアプリケーションの回路図*を追加 ... 1
- Updated pinout drawing description ... 3

Revision E (March 2013) から **Revision F** に変更 **Page**

- Changed layout of National Semiconductor Data Sheet to TI format ... 11

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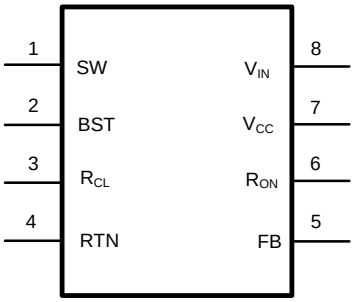
5 Pin Configuration and Functions

DGK Package and NGT Package
8-Pin VSSOP and 8-Pin WSON
Top View



Pin Functions

PIN		TYPE	DESCRIPTION	APPLICATION INFORMATION
NO.	NAME			
1	SW	O	Switching node.	Power switching node. Connect to the LC output filter.
2	BST	I	Boost bootstrap capacitor input.	An external capacitor is required between the BST and SW pins. A 0.01-µF ceramic capacitor is recommended. An internal diode between V_{CC} and BST completes the buck gate drive bias network.
3	R_{CL}	I	Current Limit OFF-time programming pin $t_{OFF} = 10^{-5} / (0.59 + (V_{FB} / 7.22 \times 10^{-6} \times R_{CL}))$	A resistor between this pin and RTN determines the variation of off-time along with the FB pin voltage per cycle while in current limit. The off-time is preset to 17 µs if FB = 0 V and decreases as the FB voltage increases.
4	RTN	—	Circuit ground.	
5	FB	I	Feedback signal from regulated output.	This pin is connected to the inverting input of the internal regulation comparator. The regulation threshold is 2.5 V.
6	R_{ON}	I	On-time set pin $t_{ON} = 1.42 \times 10^{-10} R_{ON} / V_{IN}$	A resistor between this pin and V_{IN} sets the switch on-time as a function of V_{IN}. The minimum recommended on-time is 300 ns at the maximum input voltage.
7	V_{CC}	O	Output from the internal high-voltage bias regulator. V_{CC} is nominally regulated to 7 V.	If an auxiliary voltage is available to raise the voltage on this pin, above the regulation set point (7V), the internal series pass regulator will shutdown, reducing the IC power dissipation. Do not exceed 14V. This output provides gate drive power for the internal buck switch. An internal diode is provided between this pin and the BST pin. A local 0.1-uF decoupling capacitor is recommended. The series pass regulator is current limited to 10 mA.
8	V_{IN}	I	Input supply voltage.	Recommended operating range: 9 V to 75 V.
—	EP	—	Exposed PAD, underside of the WSON-8 package option.	Internally bonded to the die substrate. Connect to GND potential for low thermal impedance.

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6 Specifications

6.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)(1).

		MIN	MAX	UNIT
	V_{IN} to RTN		80	V
	BST to RTN		94	V
	SW to RTN (steady state)	–1		V
	BST to V_{CC}		80	V
	BST to SW		14	V
	V_{CC} to RTN		14	V
	All other inputs to RTN	–0.3	7	V
	Lead temperature (soldering 4 sec)		260	°C
T_{stg}	Storage temperature	–55	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)(2)	±2000	V
		Machine model (MM)	±200	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) The human body model is a 100-pF capacitor discharge through a 1.5-kΩ resistor into each pin. The machine model is a 200-pF capacitor discharged directly into each pin. The machine model ESD compliance level for Pin 5 is 150 V. The human body ESD compliance level for Pin 7 and 8 is 1000 V.

6.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted).

		MIN	NOM	MAX	UNIT
V_{IN}	Input voltage	9		75	V
T_J	Junction temperature	−40		125	°C

6.4 Thermal Information

THERMAL METRIC(1)		LM5007		UNIT
		DGK (VSSOP)	NGT (WSON)	
		8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	158.3	38.1	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	51.3	27.8	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	78.5	15.1	°C/W
ψ_{JT}	Junction-to-top characterization parameter	4.9	0.2	°C/W
ψ_{JB}	Junction-to-board characterization parameter	77.2	15.3	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	4.5	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report (SPRA953).

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6.5 Electrical Characteristics

At T_J = 25°C, V_{IN} = 48 V (unless otherwise noted)(1).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STARTUP REGULATOR						
V_{CC}	V_{CC} Regulator Output		6.6	7	7.4	V
I_{VCC-CL}	V_{CC} Current Limit(2)			11		mA
V_{CC} SUPPLY						
$V_{CC-UVLO}$	V_{CC} Undervoltage Lockout Voltage (V_{CC} increasing)			6.3		V
$V_{CC-UVLO-HYS}$	V_{CC} Undervoltage Hysteresis			206		mV
$t_{VCC-UV-DELAY}$	V_{CC} UVLO Delay (filter)			3		µs
$I_{CC-OPER}$	I_{CC} Operating Current	Not switching, V_{FB} = 3 V		500	675	µA
I_{SHD}	Shutdown/Standby Current	V_{RON} = 0 V		100	200	µA
SWITCH CHARACTERISTICS						
$R_{DS(on)1}$	Buck Switch On-State Resistance	I_{SW} = 0.2 A, $V_{BST} – V_{SW}$ = 6.3 V(3)		0.74	1.34	Ω
$V_{GATE-UV}$	Gate Drive UVLO ($V_{BST} – V_{SW}$)	Rising	3.4	4.5	5.5	V
$V_{GATE-UV-HYS}$	Gate Drive UVLO Hysteresis			400		mV
$V_{DS((max)}$	Breakdown Voltage, V_{IN} to RTN	T_J = 25°C	80			V
		T_J = –40°C to 125°C	76			V
$V_{BST-VCC(max)}$	Breakdown voltage, BST to V_{CC}	T_J = 25°C	80			V
		T_J = –40°C to 125°C	76			V
CURRENT LIMIT						
I_{CL}	Current Limit Threshold		535	725	900	mA
$t_{CL-RESP}$	Current Limit Response Time	I_{SW} overdrive = 0.1 A, time to switch off		225		ns
$t_{CL-OFF1}$	OFF-Time Generator (test 1)	V_{FB} = 0 V, R_{CL} = 100 kΩ		17		µs
$t_{CL-OFF2}$	OFF-Time Generator (test 2)	V_{FB} = 2.3 V, R_{CL} = 100 kΩ		2.65		µs
ON-TIME GENERATOR						
t_{ON1}	TON-1	V_{IN} = 10 V, R_{ON} = 200 kΩ	2.15	2.77	3.5	µs
t_{ON2}	TON-2	V_{IN} = 75 V, R_{ON} = 200 kΩ	290	390	490	ns
V_{SHD}	Remote Shutdown Threshold	Rising	0.45	0.7	1.1	V
$V_{SHD-HYS}$	Remote Shutdown Hysteresis			40		mV
MINIMUM OFF-TIME						
$t_{OFF(min)}$	Minimum Off-Timer	V_{FB} = 0 V		300		ns
REGULATION AND OV COMPARATORS						
V_{REF}	FB Reference Threshold	Internal reference, trip point for switch ON	2.445	2.5	2.550	V
V_{OV-REF}	FB Overvoltage Threshold	Trip point for switch OFF		2.875		V
I_{FB}	FB Bias Current			100		nA
THERMAL SHUTDOWN						
T_{SHD}	Thermal Shutdown Temperature			165		°C
T_{HYS}	Thermal Shutdown Hysteresis			25		°C

(1) All electrical characteristics having room temperature limits are tested during production with $T_A = T_J$ = 25°C. All hot and cold limits are specified by correlating the electrical characteristics to process and temperature variations and applying statistical process control.
(2) The V_{CC} output is intended as a self bias for the internal gate drive power and control circuits. Device thermal limitations limit external loading.
(3) For devices in the WSON-8 package, the MOSFET $R_{DS(on)}$ limits are specified by design characterization data only.

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6.6 Typical Characteristics

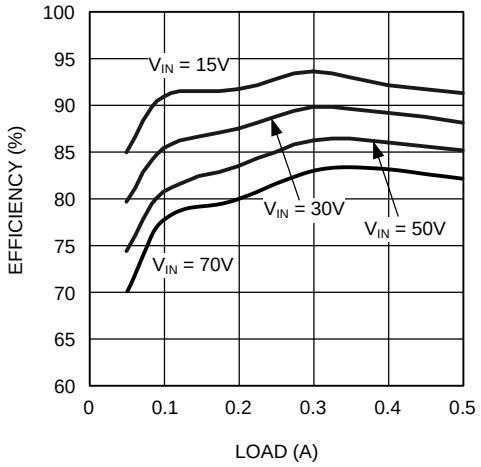
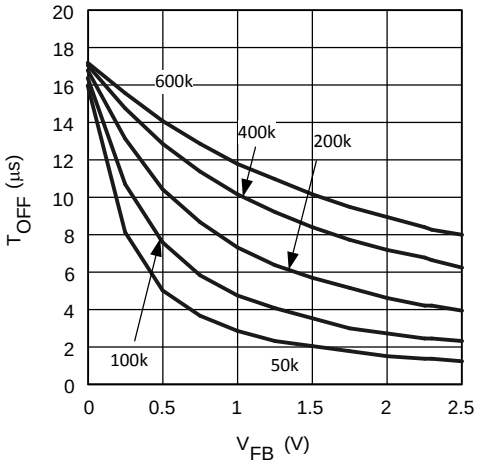
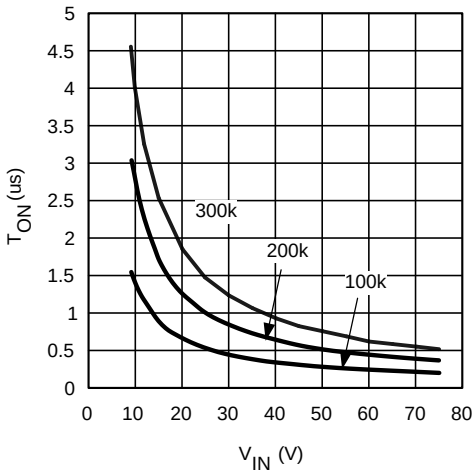


Figure 1. Converter Efficiency at 10-V Output



R_{CL} = 50 kΩ – 600 kΩ

Figure 2. Current Limit T_{OFF} vs. V_{FB}



R_{ON} = 100kΩ, 200kΩ, 300kΩ

Figure 3. T_{ON} vs. V_{IN}

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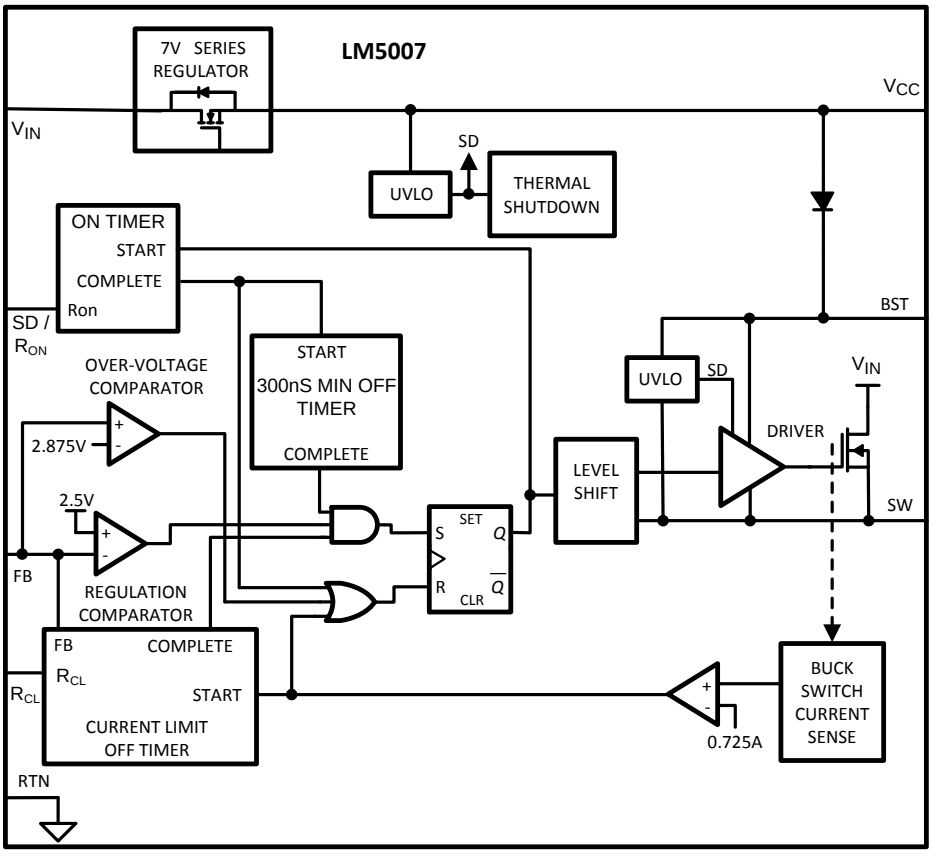
7 Detailed Description

7.1 Overview

The LM5007 regulator is an easy-to-use buck DC/DC converter that operates from 9-V to 75-V supply voltage. The device is intended for step-down conversions from 12-V, 24-V, and 48-V unregulated, semi-regulated and fully-regulated supply rails. With integrated 80-V, 0.7-A buck power MOSFET, the LM5007 delivers up to 500-mA DC load current with exceptional efficiency and low input quiescent current in a very small solution size. The device is easy to use and is provided in VSSOP-8 and thermally-enhanced WSON-8 packages. Designed for simple implementation, a nearly fixed-frequency, constant on-time (COT) operation with discontinuous conduction mode (DCM) at light loads is ideal for low-noise, high current, fast transient load requirements. Control loop compensation is not required, reducing design time and external component count. An intelligent current limit scheme is implemented in the LM5007 with forced off-time after current limit detection, which is inversely proportional to V_{OUT}. This current limiting scheme reduces load current foldback.

The LM5007 incorporates numerous other features for comprehensive system requirements, including VCC undervoltage lockout (UVLO), gate drive UVLO, maximum duty cycle limiter, intelligent current limit off-timer, and thermal shutdown with automatic recovery. These features enable a flexible and easy-to-use platform for a wide range of applications, such as 48-V telecom and the 48-V automotive power bus designs. The pin arrangement is designed for simple and optimized PCB layout, requiring only a few external components.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Hysteretic Control Circuit Overview

The LM5007 is a buck DC/DC converter that uses a constant on-time (COT) control scheme. The on-time is programmed by an external resistor and varies inversely with line input voltage (V_{IN}). The core regulation elements of the LM5007 are the feedback comparator and the programmed on-time one-shot. The regulator output voltage is sensed at the feedback pin (FB) and compared to an internal reference voltage (2.5 V). If the FB voltage is below the reference voltage, the buck switch is turned on for a fixed time interval determined by the input voltage and a programming resistor (R_{ON}). Following the on period, the switch remains off for at least the minimum off-time interval of 300 ns. If the FB voltage is still below the reference after the 300-ns off-time, the switch turns on again for another on-time interval. This switching behavior continues until the FB voltage reaches the reference voltage level.

The LM5007 operates in discontinuous conduction mode (DCM) at light load currents and continuous conduction mode (CCM) at heavier load currents. In DCM, current through the output inductor starts at zero and ramps up to a peak value during the buck switch on-time and then back to zero during the off-time. The inductor current remains at zero until the next on-time interval begins when FB falls below the internal reference voltage. The operating frequency in DCM is relatively low and varies with load. Thus, the conversion efficiency is maintained at light loads, since the switching losses decrease with the reduction in load current and switching frequency. Calculate the approximate switching frequency in DCM with Equation 1.

$$F_{SW(DCM)} = \frac{{V_{OUT}}^2 \cdot L_O}{R_{LOAD} \cdot {R_{ON}}^2} \cdot 10^{20} \quad (1)$$

In CCM, current flows continuously through the inductor and never ramps down to zero. The switching frequency in CCM is greater than that in DCM and remains relatively constant with load and line variations. Calculate the approximate switching frequency in CCM with Equation 2.

$$F_{SW(CCM)} = \frac{V_{OUT}}{1.42 \cdot 10^{-10} \cdot R_{ON}} \quad (2)$$

The output voltage (V_{OUT}) can be programmed by two external resistors as shown in Figure 4. Calculate the output voltage setpoint using Equation 3.

$$V_{OUT} = 2.5\,V \cdot \left(1 + \frac{R_1}{R_2}\right) \quad (3)$$

The feedback comparator in hysteretic regulators depend upon the output ripple voltage to switch the power MOSFET on and off at regular intervals. In order for the internal comparator to respond quickly to changes in output voltage, proportional to inductor current, a minimum amount of capacitor Equivalent Series Resistance (ESR) is required. A ripple voltage of 25 mV to 50 mV is recommended at the feedback pin (FB) for stable operation. In cases where the intrinsic capacitor ESR is too small, additional series resistance may be added.

For applications where lower output voltage ripple is required, the load can be connected directly to the low ESR output capacitor as shown in Figure 4. The series resistor (R) will degrade the load regulation. Another technique for enhancing the ripple voltage at FB is to place a capacitor in parallel with the upper feedback resistor, R1. The addition of this feedforward capacitor reduces the attenuation of the ripple voltage from the feedback divider.

7.3.2 High-Voltage Bias Supply Regulator

The LM5007 contains an internal high-voltage bias supply regulator. The input pin (V_{IN}) can be connected directly to line voltages from 9 V to 75 V. To avoid supply voltage transients due to long lead inductances on the input pin (V_{IN}), it is always recommended to connect a low-ESR ceramic capacitor (≈ 0.1 µF) between V_{IN} and RTN, located close to the respective pins of the LM5007. The bias regulator is internally current limited to 10 mA. Upon power up, the regulator is enabled and sources current into an external capacitor connected to the V_{CC} pin. When the V_{CC} voltage reaches the regulation point of 7 V, the controller output is enabled.

An external auxiliary supply voltage can be applied to the V_{CC} pin. If this auxiliary voltage is greater than 7 V, the internal regulator will essentially shutoff, thus reducing internal power dissipation.

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Feature Description (continued)

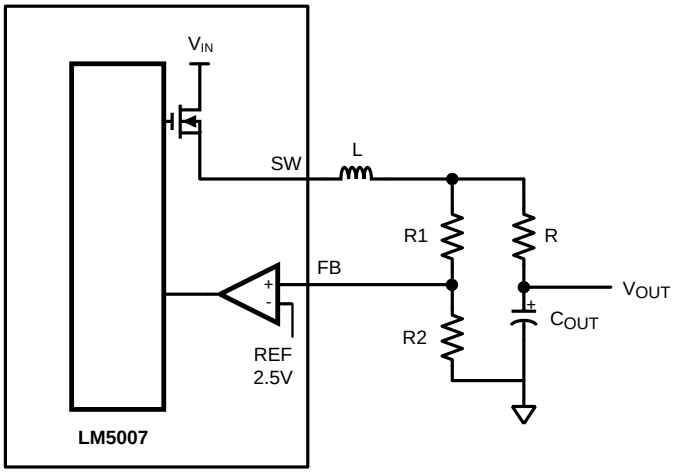

Figure 4. Low Output Ripple Voltage Configuration

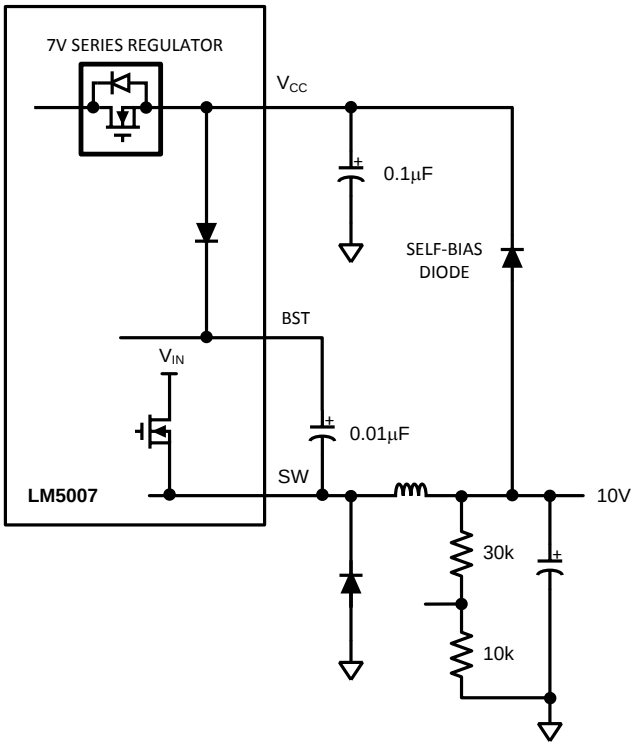

Figure 5. Self-Biased Configuration with V_{OUT} Feeding V_{CC} Through a Diode

7.3.3 Overvoltage Comparator

The overvoltage comparator is provided to protect the output from overvoltage conditions due to sudden input line voltage changes or output loading changes. The overvoltage comparator monitors the FB voltage relative to an internal 2.875-V reference, V_{OV-REF}. If the voltage at FB rises above V_{OV-REF}, the comparator immediately terminates the buck switch on-time pulse.

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Feature Description (continued)

7.3.4 On-Time Generator and Shutdown

The on-time of the LM5007 is set inversely proportional to the input voltage by an external resistor connected between V_{IN} and R_{ON}. The R_{ON} pin is a low impedance input biased at approximately 1.5 V. Thus, the current through the resistor and into the R_{ON} pin is approximately proportional to V_{IN} and used internally to control the on-timer. This scheme of input voltage feedforward hysteretic operation achieves nearly constant switching frequency over varying line and load conditions. Equation 4 specifies the on-time equation for the LM5007.

$$t_{ON} = 1.42 \cdot 10^{-10} \cdot \frac{R_{ON}}{V_{IN}} \tag{4}$$

The R_{ON} pin of the LM5007 also provides a shutdown function that disables the converter and significantly decreases quiescent power dissipation. Pulling the voltage at R_{ON} below a 0.7-V logic threshold activates a low-power shutdown mode. The V_{IN} quiescent current in this shutdown mode is approximately 100 µA internal to the LM5007 plus the current in the R_{ON} resistor.

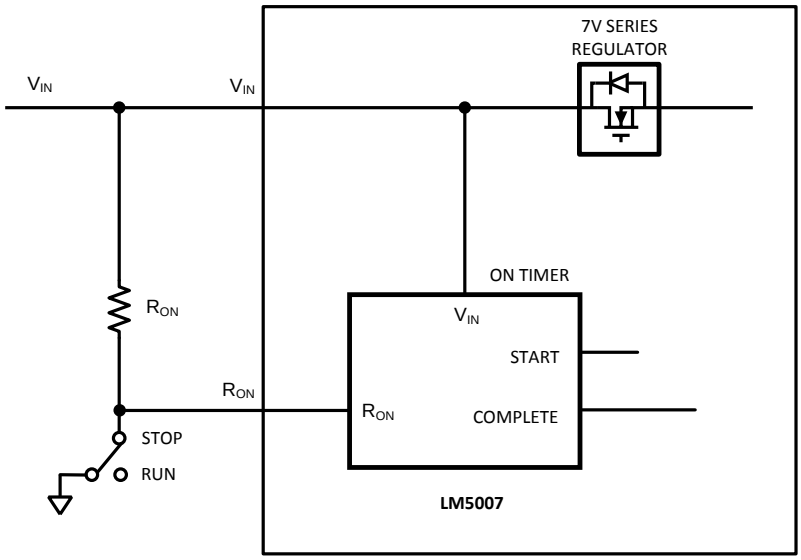

Figure 6. Shutdown Implementation

7.3.5 Overcurrent Protection

The LM5007 contains an intelligent current limit off-timer intended to reduce the foldback characteristic inherent with fixed off-time overcurrent protection (OCP) schemes. If the current in the buck switch exceeds 725 mA, the present cycle on-time is immediately terminated (cycle-by-cycle current limit). Following the termination of the cycle a non-resettable current limit off-timer is initiated. The duration of the off-time is a function of the external resistor (R_{CL}) and the FB voltage. When the FB voltage equals zero, the current limit off-time is internally preset to 17 µs. This condition occurs during a short-circuit condition when a maximum amount of off-time is required.

In case of output overload (not a complete short circuit), the current limit off-time is reduced as a function of the output voltage (measured at the FB pin). Scaling the off-time with smaller overloads reduces the amount of foldback and also reduces the initial start-up time. Calculate the current limit off-time for a given FB voltage and R_{CL} resistor using Equation 5.

$$t_{OFF(CL)} = \cdot \frac{10^{-5}}{0.59 + \frac{V_{FB}}{7.22 \cdot 10^{-6} \cdot R_{CL}}} \tag{5}$$

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Feature Description (continued)

Select the current limit off-time such that it is less than the MOSFET off-time during normal steady-state switching operation. Applications utilizing low-resistance inductors and/or a low-voltage-drop freewheeling power diodes may require special evaluation at high line, short-circuited conditions. In this special case the preset 17-µs off-time (V_{FB} = 0 V) may be insufficient to provide inductor volt-seconds balance. Additional inductor resistance, output resistance or a larger voltage drop diode may be necessary to balance inductor volt-seconds and limit the short-circuit current.

7.3.6 N-Channel Buck Switch and Driver

The LM5007 integrates an N-channel buck switch and associated floating high voltage gate driver. This gate driver circuit works in conjunction with an external bootstrap capacitor and an internal high voltage diode. The bootstrap capacitor is charged by V_{CC} through the internal high voltage diode. A 0.01-µF ceramic capacitor connected between BST and SW is recommended.

During each cycle when the buck switch turns off, the SW voltage is approximately 0 V. When the SW voltage is low, the bootstrap capacitor is charged from V_{CC} through the internal bootstrap diode. The minimum off-timer, set to 300 ns, ensures that there is a minimum interval every switching cycle to recharge the bootstrap capacitor.

An external recirculating diode from the SW to RTN is necessary to carry the inductor current after the internal buck switch turns off. This external diode must be an ultra-fast switching or Schottky type to reduce turn-on losses and switch current overshoot. The reverse voltage rating of the recirculating diode must be greater than the maximum line input voltage.

7.3.7 Thermal Protection

Internal thermal shutdown circuitry is provided to protect the integrated circuit in the event the maximum junction temperature is exceeded. When thermal protection is activated, typically at 165°C, the converter is forced into a low power reset state, disabling the output driver. This feature is provided to prevent catastrophic failures from accidental device overheating.

7.3.8 Minimum Load Current

A minimum load current of 1 mA is required to maintain proper operation. If the load current falls below that level, the bootstrap capacitor may discharge during the long off-time, and the circuit will either shutdown or cycle on and off at a low frequency. If the load current is expected to drop below 1 mA in the application, choose the feedback resistors with sufficiently low value to provide the minimum required load current at nominal V_{OUT}.

7.3.9 Ripple Configuration

The LM5007 uses an adaptive constant on-time (COT) control in which the conduction time of the buck MOSFET is terminated by an on-timer and the off-time is terminated by the feedback voltage (V_{FB}) falling below the reference voltage (V_{REF}). Therefore, for stable operation, the feedback voltage must decrease monotonically and in phase with the inductor current during the off-time interval. Furthermore, this change in feedback voltage (V_{FB}) during the off-time must be larger than any noise component present at the feedback node.

Table 1 shows three different methods for generating appropriate voltage ripple at the feedback node. Type 1 and Type 2 ripple circuits couple the ripple at the output of the converter to the feedback node (FB). The output voltage ripple has two components:

1. Capacitive ripple caused by the inductor current ripple charging/discharging the output capacitor.
2. Resistive ripple caused by the inductor current ripple flowing through the ESR of the output capacitor.

The capacitive ripple is not in phase with the inductor current. As a result, the capacitive ripple does not decrease monotonically during the off-time. The resistive ripple is in phase with the inductor current and decreases monotonically during the off-time. The resistive ripple must exceed the capacitive ripple at the output node (V_{OUT}) for stable operation. If this condition is not satisfied, unstable switching behavior is observed in COT converters with multiple on-time bursts in close succession followed by a long off-time.

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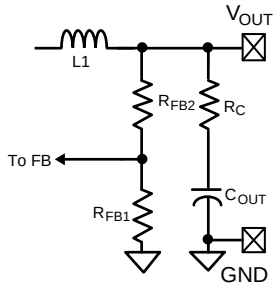
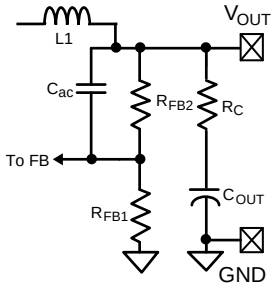
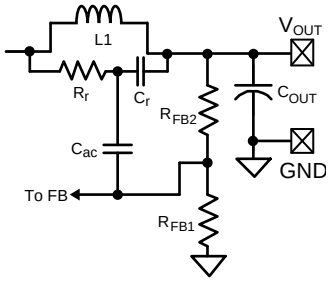
Feature Description (continued)

Type 3 ripple method uses R_r and C_r and the switch node (SW) voltage to generate a triangular ramp. This triangular ramp is ac coupled using C_{ac} to the feedback node (FB). Since this circuit does not use the output voltage ripple, it is ideally suited for applications where low output voltage ripple is required. See *AN-1481 Controlling Output Ripple and Achieving ESR Independence in Constant On-Time (COT) Regulator Designs* (SNVA166) for more details for each ripple generation method.

Table 1. Ripple Configuration

TYPE 1 LOWEST COST CONFIGURATION	TYPE 2 REDUCED RIPPLE CONFIGURATION	TYPE 3 MINIMUM RIPPLE CONFIGURATION
		
$R_C = \frac{25mV}{\Delta I_{L(min)}} \cdot \frac{V_{OUT}}{V_{REF}}$ (6)	$C_{ac} \geq \frac{5}{F_{SW} \cdot \left(R_{FB1} \| R_{FB2}\right)}$ $R_C = \frac{25mV}{\Delta I_{L(min)}}$ (7)	$C_r = 3.3nF$ $C_{ac} = 100nF$ $R_r \cdot C_r = \frac{\left(V_{IN(min)} - V_{OUT}\right) \cdot t_{ON}}{25mV}$ (8)

7.4 Device Functional Modes

7.4.1 Standby Mode with V_{IN}

The LM5007 is intended to operate with input voltages above 9 V. The minimum operating input voltage is determined by the V_{CC} undervoltage lockout threshold of 6.3 V (typ). If V_{IN} is too low to support a V_{CC} voltage greater than the V_{CC} UVLO threshold, the converter switches to its standby mode with the buck switch in the off state.

7.4.2 Shutdown Mode

The LM5007 is in shutdown mode when the R_{ON} pin is pulled below 0.7 V (typ). In this mode, the buck MOSFET is held off and the V_{CC} regulator is disabled.

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8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The LM5007 requires only a few external components to convert from a wide range of supply voltages to a fixed output voltage. To expedite and streamline the process of designing a LM5007-based converter, a comprehensive LM5007 quick-start calculator is available for download to assist the designer with component selection for a given application. WEBENCH® online software is also available to generate complete designs, leveraging iterative design procedures and access to comprehensive component databases. The following sections discuss a design procedure using a typical application example. Figure 7 shows the LM5007 in a configuration suitable for several application use cases. See the LM5007 EVM for more details.

8.2 Typical Application

The application schematic of an LM5007-based buck converter is shown in Figure 7. For an output voltage (V_{OUT}) above the maximum regulation threshold of V_{CC} (see *Electrical Characteristics*), the V_{CC} pin can be supplied from V_{OUT} through a diode for higher efficiency and lower power dissipation in the IC.

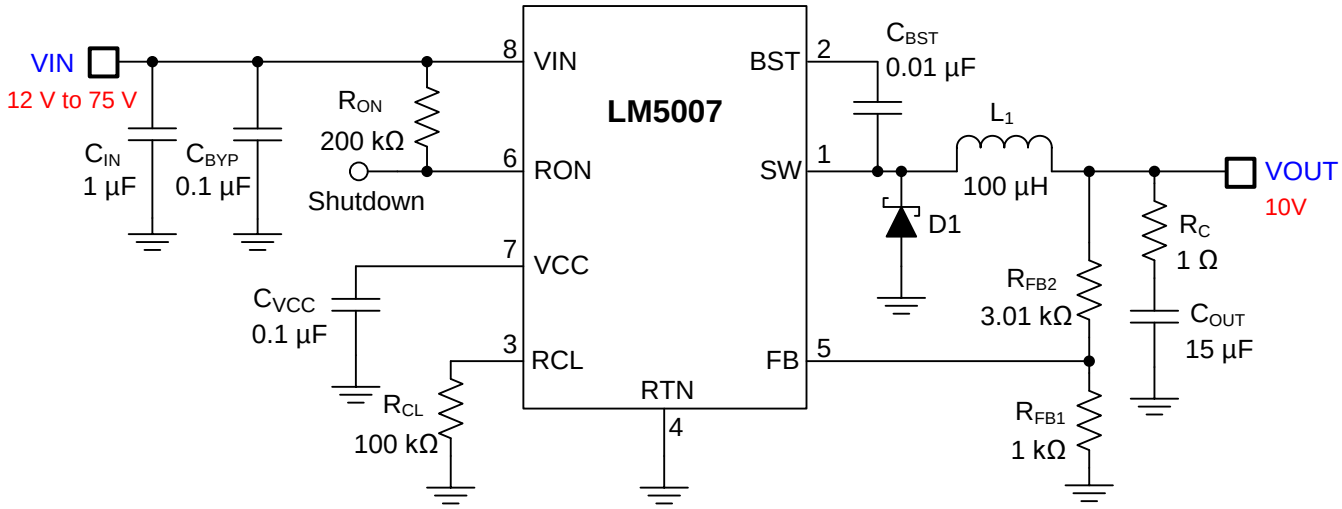

Figure 7. 12-V to 75-V Input and 10-V, 400-mA Output Buck Converter

8.2.1 Design Requirements

For this design example, use the parameters listed in Table 2 as the input parameters.

Table 2. Design Parameters

DESIGN PARAMETERS	VALUE
Input Voltage	12 V to 75 V
Output Voltage	10 V
Maximum Output Current	400 mA
Nominal Switching Frequency	380 kHz

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8.2.2 Detailed Design Procedure

8.2.2.1 Custom Design With WEBENCH® Tools

Click here to create a custom design using the LM5007 device with WEBENCH® Power Designer.

1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

8.2.2.2 Custom Design With Excel Quickstart Tool

Select components based on the converter specifications using the LM5007 quick-start calculator available for download from the LM5007 product folder.

8.2.2.3 Feedback Resistors, R_{FB1} and R_{FB2}

$V_{OUT} = V_{FB} \times (R_{FB2}/R_{FB1} + 1)$, and since V_{FB} = 2.5 V in regulation, the ratio of R_{FB2} to R_{FB1} is 3 : 1. Select standard values of R_{FB1} = 1 kΩ and R_{FB2} = 3.01 kΩ. Other values can be chosen as long as the 3 : 1 ratio is maintained.

8.2.2.4 Switching Frequency Selection, R_{ON}

Set the switching frequency by resistor R_{ON} using Equation 9.

$$R_{ON} = \frac{V_{OUT}}{1.42 \cdot 10^{-10} \cdot F_{SW}} \tag{9}$$

Selecting F_{SW} = 380 kHz results in R_{ON}= 185 kΩ. Choose a standard value of 200 kΩ for this design.

8.2.2.5 Buck Inductor, L_1

The inductor is selected to provide a current ripple of 40% to 50% of the full-load current. In addition, the peak inductor current at maximum load must be smaller than the minimum current limit threshold provided in *Electrical Characteristics*. The inductor current ripple is given by Equation 10.

$$\Delta I_L = \frac{V_{IN} - V_{OUT}}{L_1 \cdot F_{SW}} \cdot \frac{V_{OUT}}{V_{IN}} \tag{10}$$

The maximum ripple is observed at the maximum input voltage. Using V_{IN} = 75 V and ΔI_L= 50% x $I_{OUT(max)}$ results in L_1 = 114 µH. Select a standard inductor value of 100 µH. The inductor current ripple ranges from 88 mA to 228 mA depending on input voltage. The peak inductor and switch current at full load are given by Equation 11.

$$I_{L1(peak)} = I_{OUT(max)} + \frac{\Delta I_L}{2} \tag{11}$$

At maximum V_{IN}, the peak inductor current is 514 mA, which is lower than the minimum current limit threshold of 535 mA. The selected inductor should be able to operate at the maximum current limit of 900 mA without saturation during startup and overload conditions.

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8.2.2.6 Output Capacitor, C_{OUT}

Select the output capacitor to minimize the capacitive ripple. The maximum ripple is observed at the maximum input voltage and is given by Equation 12.

$$C_{OUT} = \frac{\Delta I_L}{8 \cdot F_{SW} \cdot \Delta V_{COUT}}$$

where

- ΔV_{COUT} is the voltage ripple across the capacitor,
- ΔI_L is the peak-to-peak inductor ripple current. (12)

Substituting V_{IN} = 75 V and targeting ΔV_{COUT}= 10 mV gives C_{OUT} = 7.5 µF. Select a standard 15-µF value for C_{OUT} with X5R or X7R dielectric and a voltage rating of 16 V or higher.

8.2.2.7 Type I Ripple Circuit, R_C

Choose a type I ripple circuit, as described in Ripple Configuration, for this example. For a constant on-time (COT) converter to be stable, the injected in-phase ripple must be larger than the capacitive ripple on C_{OUT}.

Using the type I ripple circuit equations with minimum FB pin ripple of 25 mV, calculate the value of series resistor R_C using Equation 13.

$$R_C = \frac{25\,mV}{\Delta I_{L(min)}} \cdot \frac{V_{OUT}}{V_{REF}} \tag{13}$$

Based on the calculated value of 1.1 Ω, select a standard value of 1 Ω.

8.2.2.8 Input Capacitor, C_{IN}

The input capacitor should be large enough to limit the input voltage ripple that can be calculated using Equation 14.

$$C_{IN} = \frac{I_{OUT(max)} \cdot D \cdot (1 - D)}{F_{SW} \cdot \Delta V_{CIN}} \tag{14}$$

The input ripple reaches its maximum at D = 0.5. Targeting a ΔV_{CIN} = 0.5 V at using a duty cycle of D = 0.5 results in C_{IN} = 0.526 µF. A standard value of 1 µF is selected. The input capacitor should be rated for the maximum input voltage under all conditions. A 100-V, X7R type capacitor is selected for this design. The input capacitor should be placed close to the V_{IN} pin and the anode of the diode (D1) as it supplies high-frequency switching current.

Also place a 0.1-µF bypass capacitor (C_{BYP}) very close to V_{IN} and RTN pins of the IC to reduce switching power loop parasitic inductance and mitigate SW node overshoot and ringing.

8.2.2.9 Current Limit, R_{CL}

Resistor R_{CL} sets the current limit off-timer according to Equation 5. The useable values tend to be in the range of 100 kΩ to 1 MΩ. Equation 15 specifies the off-time required for volt-second balance on the inductor in current limit.

$$t_{OFF(ILIM)} = \frac{V_{IN(max)} \cdot 225\,ns}{V_{OUT} + V_F + I_{LIM} \cdot R_{DCR}}$$

where

- 225 ns is the current limit response time,
- V_F is the forward voltage drop of the freewheeling power diode,
- V_{OUT} is the output voltage,
- I_{LIM} is the current limit,
- R_{DCR} is the inductor DC resistance. (15)

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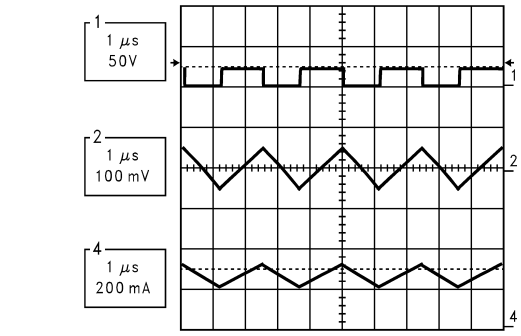
The programmed current limit off-time should be higher than the off-time needed for volt-second balance on the inductor. For a short at the output (V_{OUT} = 0 V) and V_F = 0.7 V, an inductor DCR of 390 mΩ or higher is needed to achieve volt-second balance at the maximum programmed current limit off-time of 17 µs. Using Equation 5, an R_{CL} of greater than 10 kΩ can be used. Select a conservative value of 100 kΩ for this design.

For step-by-step design procedures, circuit schematics, bill of materials, PCB files, simulation and test results of LM5007-powered implementations, refer to the *TI Designs* reference design library.

8.2.3 Application Curves

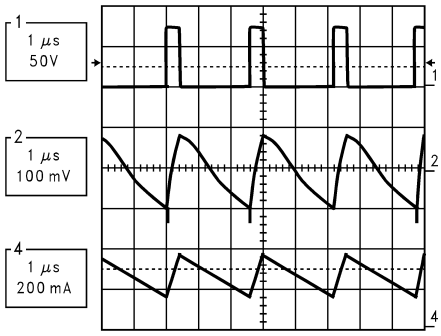


V_{OUT} = 10 V
CH1: Switch Node

V_{IN} = 20 V
CH2: V_{OUT} (AC)

I_{OUT} = 250 mA
CH4: Inductor Current

Figure 8. Switching Waveforms, V_{IN} = 20 V



V_{OUT} = 10 V
CH1: Switch Node

V_{IN} = 75 V
CH2: V_{OUT} (AC)

I_{OUT} = 250 mA
CH4: Inductor Current

Figure 9. Switching Waveforms, V_{IN} = 75 V

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9 Power Supply Recommendations

The LM5007 converter is designed to operate from a wide input voltage range from 9 V to 75 V. The characteristics of the input supply must be compatible with the *Absolute Maximum Ratings* and *Recommended Operating Conditions*. In addition, the input supply must be capable of delivering the required input current to the fully-loaded regulator. Estimate the average input current with Equation 16.

$$I_{IN} = \frac{V_{OUT} \cdot I_{OUT}}{V_{IN} \cdot \eta}$$

where

- η is the efficiency (16)

If the converter is connected to an input supply through long wires or PCB traces with large impedance, achieving stable performance requires special care. The parasitic inductance and resistance of the input cables may have an adverse affect on converter operation. The parasitic inductance in combination with the low-ESR ceramic input capacitors form an underdamped resonant circuit. This circuit can cause overvoltage transients at VIN each time the input supply is cycled ON and OFF. The parasitic resistance causes the input voltage to dip during a load transient. If the regulator is operating close to the minimum input voltage, this dip can cause false UVLO fault triggering and a system reset. The best way to solve such issues is to reduce the distance from the input supply to the regulator and use an aluminum or tantalum input capacitor in parallel with the ceramics. The moderate ESR of the electrolytic capacitors helps to damp the input resonant circuit and reduce any voltage overshoots. A capacitance in the range of 10 µF to 47 µF is usually sufficient to provide input damping and helps to hold the input voltage steady during large load transients.

An EMI input filter is often used in front of the regulator that, unless carefully designed, can lead to instability as well as some of the effects mentioned above. The user's guide *Simple Success with Conducted EMI for DC-DC Converters* (SNVA489) provides helpful suggestions when designing an input filter for any switching regulator.

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10 Layout

10.1 Layout Guidelines

The LM5007 regulation and overvoltage comparators are very fast, and as such respond to short-duration noise pulses. Layout considerations are therefore critical for optimum performance:

1. Minimize the area of the high di/dt switching current loop consisting of the VIN and SW pins, freewheeling power diode, and input ceramic capacitor. Keep the input capacitor(s) close to the VIN pin of the LM5007. Place the cathode of the freewheeling diode close to the SW pin and and its anode near the return terminal of the input capacitor as illustrated in Figure 10. Route a short, direct connection to the RTN pin using polygon copper pours under the IC.
2. Place the inductor close to the SW pin of the LM5007. Minimize SW node copper area to reduce radiated noise related to high dv/dt.
3. Locate C_{BST}, R_{CL}, R_{ON} and C_{VCC} components as physically close as possible to their respective pins, thereby minimizing noise pickup in the printed-circuit tracks.
4. Locate the VOUT sense trace away from noise sources such as inductors. Place both feedback resistors close to the FB pin to minimize the length of the FB trace.
5. Place a solid GND plane on layer 2 of the PCB.

If the internal dissipation of the LM5007 converter produces excessive junction temperatures during normal operation, optimal use of the PCB ground plane can help considerably to dissipate heat. The exposed pad on the bottom of the WSON-8 package can be soldered to a ground plane on the PCB, and that plane should extend out from beneath the IC to help dissipate the heat. Additionally, the use of wide PCB traces for power connection can also help conduct heat away from the IC. Judicious positioning of the LM5007 converter within the end product, along with use of any available air flow (forced or natural convection), can help reduce the operating junction temperature.

10.2 Layout Example

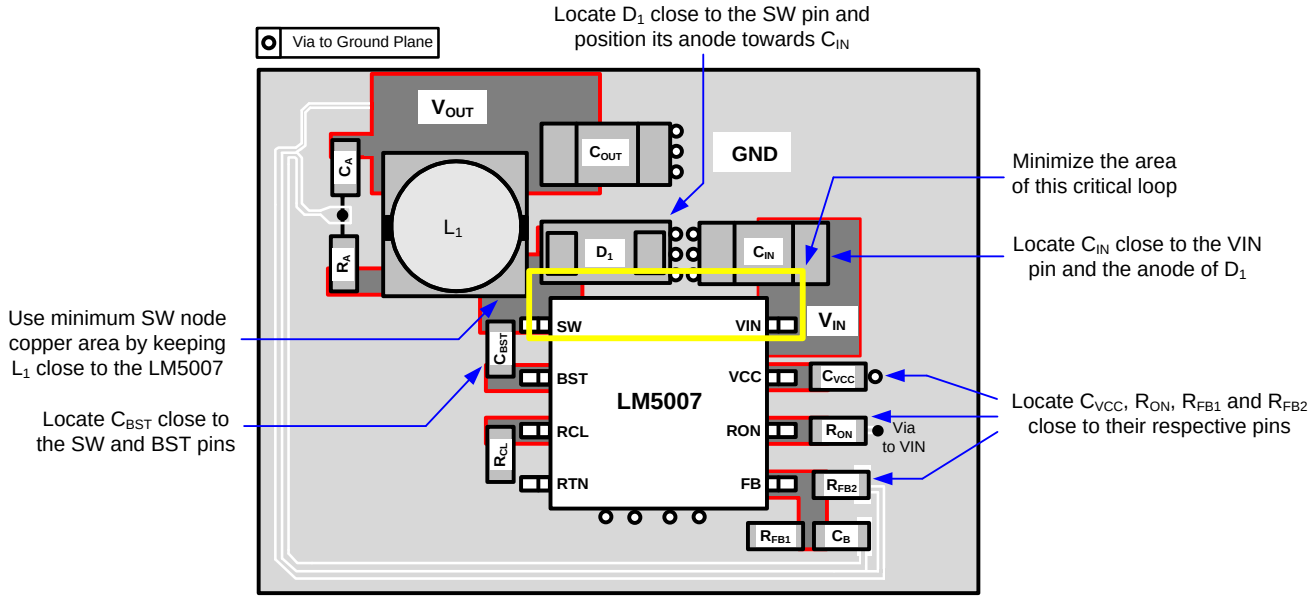

Figure 10. PCB Layout Example

NOTE

It is critical to minimize switching loop parasitic inductance by locating the input capacitor close to the VIN pin of the LM5007. Also, place the freewheeling power diode near the SW pin with its anode adjacent to the input capacitor as shown in Figure 10.

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11 デバイスおよびドキュメントのサポート

11.1 デバイス・サポート

11.1.1 デベロッパー・ネットワークの製品に関する免責事項

デベロッパー・ネットワークの製品またはサービスに関するTIの出版物は、単独またはTIの製品、サービスと一緒に提供される場合に関係なく、デベロッパー・ネットワークの製品またはサービスの適合性に関する是認、デベロッパー・ネットワークの製品またはサービスの是認の表明を意味するものではありません。

11.1.2 WEBENCH®ツールによるカスタム設計

ここをクリックすると、WEBENCH® Power Designerにより、LM5007を使用するカスタム設計を作成できます。

1. 最初に、入力電圧(V_{IN})、出力電圧(V_{OUT})、出力電流(I_{OUT})の要件を入力します。
2. オプティマイザのダイヤルを使用して、効率、占有面積、コストなどの主要なパラメータについて設計を最適化します。
3. 生成された設計を、テキサス・インスツルメンツが提供する他の方式と比較します。

WEBENCH Power Designerでは、カスタマイズされた回路図と部品リストを、リアルタイムの価格と部品の在庫情報と併せて参照できます。

通常、次の操作を実行可能です。

- 電気的なシミュレーションを実行し、重要な波形と回路の性能を確認する。
- 熱シミュレーションを実行し、基板の熱特性を把握する。
- カスタマイズされた回路図やレイアウトを、一般的なCADフォーマットで出力する。
- 設計のレポートをPDFで印刷し、設計を共有する。

WEBENCHツールの詳細は、www.ti.com/WEBENCHでご覧になれます。

11.1.3 開発サポート

開発サポートについては、以下を参照してください。

- TIのリファレンス・デザイン・ライブラリについては、TI Designsを参照してください。
- TIのWEBENCH設計環境については、WEBENCH®設計センターを参照してください。

11.2 ドキュメントのサポート

11.2.1 関連資料

関連資料については、以下を参照してください。

- *LM5007クイック・スタート・カリキュレータ*
- *LM5007EVAL評価ボード*
- *LM5007SD-EVAL評価ボード*
- *LM5006EVAL評価ボード*
- *LM5008EVAL評価ボード*
- *LM5008AEVAL評価ボード*
- *LM5009EVAL評価ボード*
- *LM5010-EVAL評価ボード*
- *LM5010AEVAL評価ボード*
- *『広い入力/出力電圧差動用の降圧レギュレータ・トポロジ』*(SNVA594)
- *『AN-1481コンスタント・オンタイム(COT)方式のレギュレータにおける出力リップルの制御とESRの独立性確保』*(SNVA166)
- ホワイト・ペーパー
  - *『コスト効率の優れた、要求の厳しいアプリケーション用の広V_{IN}、低EMIの同期整流降圧回路の評価』*(SLYY104)
  - *『電源の伝導EMI仕様の概要』*(SLYY136)
  - *『電源の放射EMI仕様の概要』*(SLYY142)
- TI Designs:
  - *『PoE PSE タイプ2 (30W) IEEE 802.3at完全自律型Quadポート・ソリューション』*

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ドキュメントのサポート (continued)

- *『デジタル出力モジュール向け8チャネル、2Aハイサイド・ドライバのリファレンス・デザイン』*
- *『ロー・サイド0.5A 8チャネル・デジタル出力モジュール、PLC用』*
- *『デジタル入力/処理機能内蔵Hi-Fi 175W Class-Dオーディオ・アンプのリファレンス・デザイン』*
- *『12V/48V車載システム向け双方向DC/DCコンバータのリファレンス・デザイン』*

11.2.1.1 PCBレイアウトについてのリソース

- *『AN-1149 スイッチング電源のレイアウトのガイドライン』*(SNVA021)
- *『AN-1229 Simple Switcher PCBレイアウト・ガイドライン』*(SNVA054)
- *『独自電源の構築 - レイアウトの考慮事項』*(SLUP230)
- *『LM4360xおよびLM4600xによる低放射EMIレイアウトの簡単な作成』*(SNVA721)
- *『AN-2162 DC/DCコンバータから伝導されるEMIでの簡単な成功』*(SNVA489)
- *『誘導性寄生の最小化による降圧コンバータのEMIおよび電圧ストレスの低減』*(SLYT682)
- Power Houseブログ
  - *『DC/DCコンバータの高密度PCBレイアウト』*

11.2.1.2 熱設計についてのリソース

- *『AN-2020 システムの基本設計に応じた熱設計』*(SNVA419)
- *『AN-1520 露出パッド・パッケージで最良の熱抵抗を実現するための基板レイアウト・ガイド』*(SNVA183)
- *『半導体とICパッケージの熱指標』*(SPRA953)
- *『LM43603およびLM43602による簡単な熱設計』*(SNVA719)
- *『放熱特性の優れたPowerPAD™パッケージ』*(SLMA002)
- *『PowerPADの簡単な使用法』*(SLMA004)
- *『新しい熱測定基準の使用』*(SBVA025)

11.3 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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11.4 商標

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11.6 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

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12 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、そのデバイスについて利用可能な最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM5007MM/NOPB	Active	Production	VSSOP (DGK) | 8	1000 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	S81B
LM5007MM/NOPB.A	Active	Production	VSSOP (DGK) | 8	1000 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	S81B
LM5007MM/NOPB.B	Active	Production	VSSOP (DGK) | 8	1000 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	S81B
LM5007MMX/NOPB	Active	Production	VSSOP (DGK) | 8	3500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	S81B
LM5007MMX/NOPB.A	Active	Production	VSSOP (DGK) | 8	3500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	S81B
LM5007MMX/NOPB.B	Active	Production	VSSOP (DGK) | 8	3500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	S81B
LM5007SD/NOPB	Active	Production	WSON (NGT) | 8	1000 | SMALL T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	L00031B
LM5007SD/NOPB.A	Active	Production	WSON (NGT) | 8	1000 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	L00031B
LM5007SD/NOPB.B	Active	Production	WSON (NGT) | 8	1000 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	L00031B
LM5007SDX/NOPB	Active	Production	WSON (NGT) | 8	4500 | LARGE T&R	Yes	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	L00031B
LM5007SDX/NOPB.A	Active	Production	WSON (NGT) | 8	4500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	L00031B
LM5007SDX/NOPB.B	Active	Production	WSON (NGT) | 8	4500 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	L00031B

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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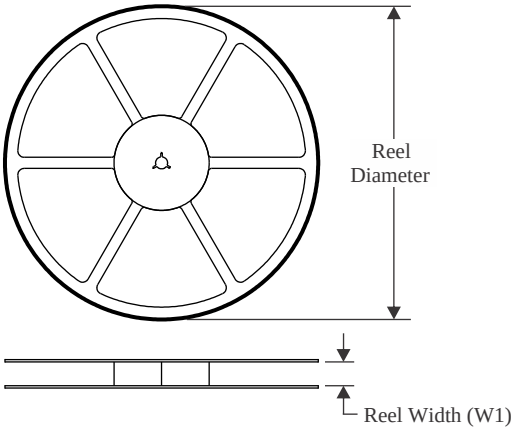
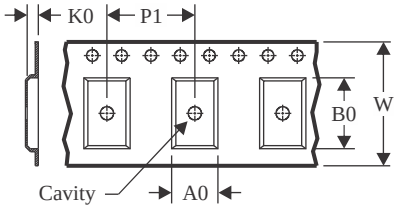
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

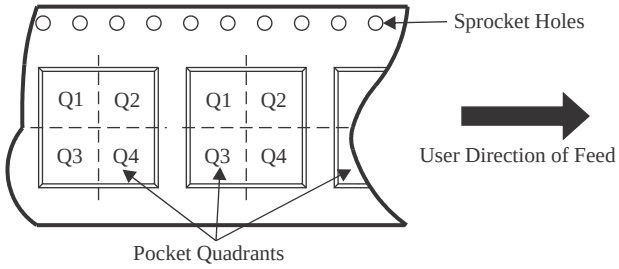


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

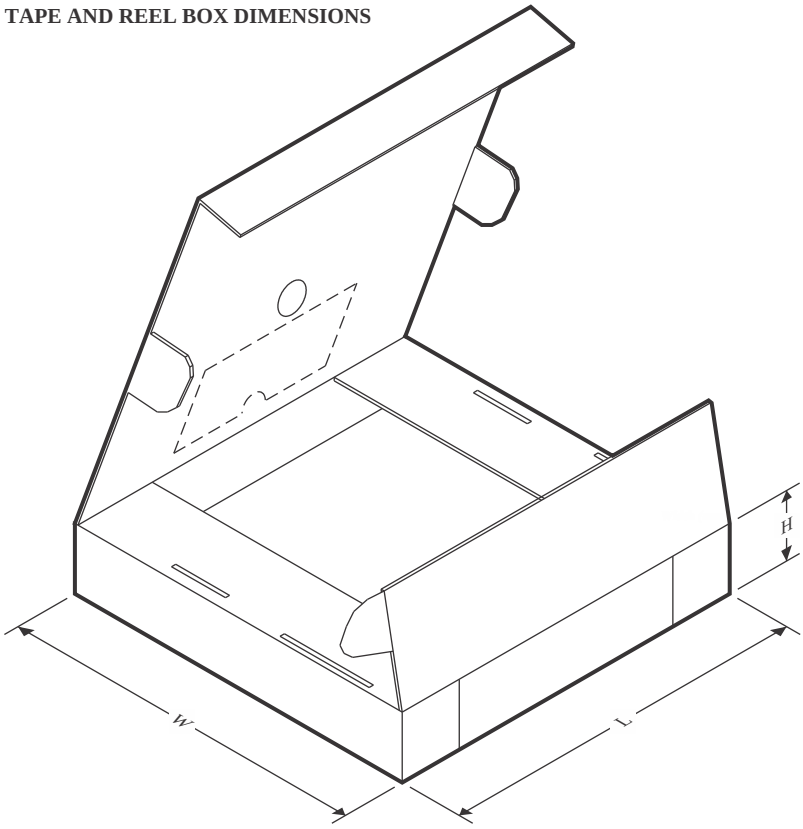
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM5007MM/NOPB	VSSOP	DGK	8	1000	177.8	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM5007MMX/NOPB	VSSOP	DGK	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM5007SD/NOPB	WSON	NGT	8	1000	177.8	12.4	4.3	4.3	1.3	8.0	12.0	Q1
LM5007SDX/NOPB	WSON	NGT	8	4500	330.0	12.4	4.3	4.3	1.3	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

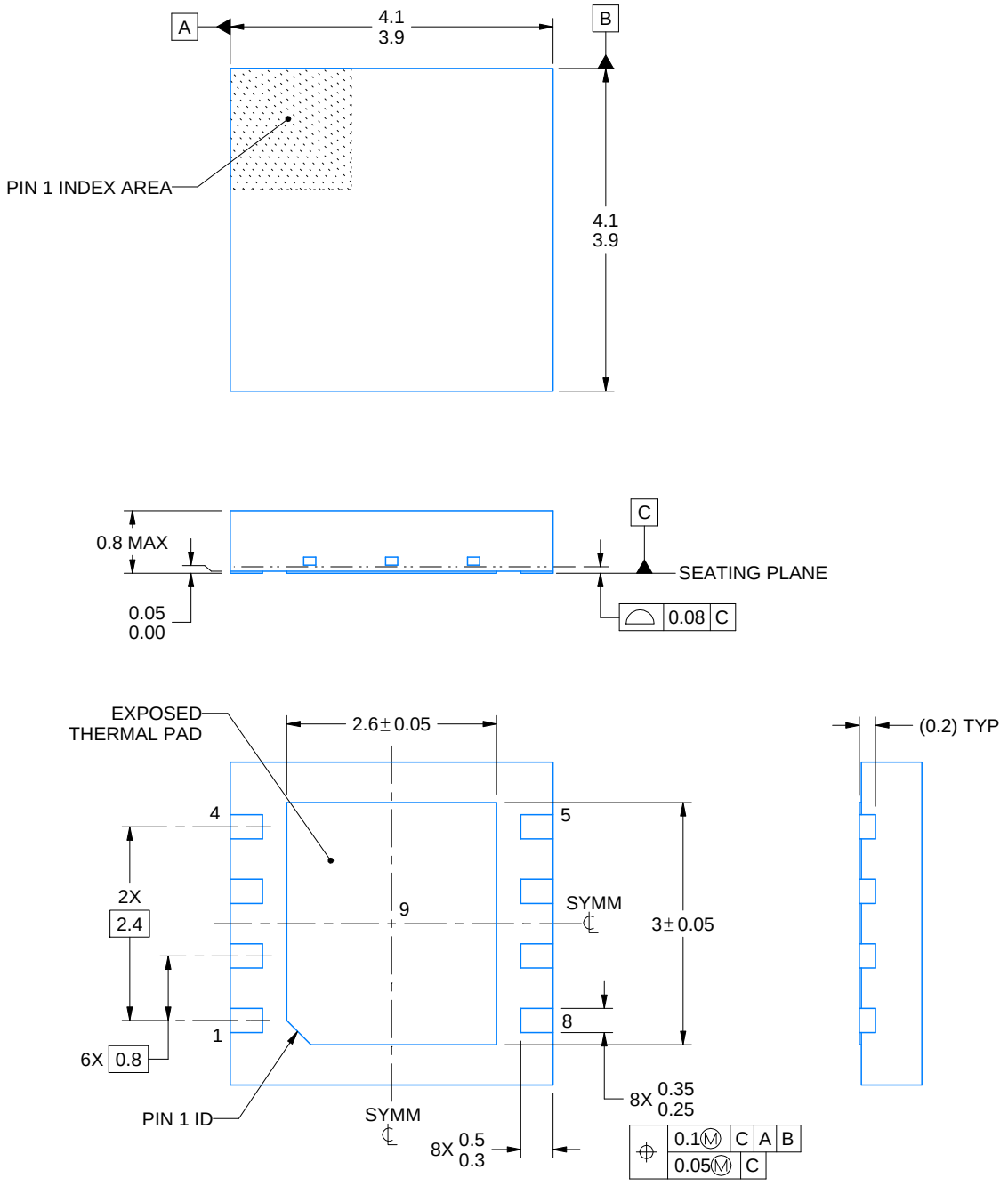
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM5007MM/NOPB	VSSOP	DGK	8	1000	208.0	191.0	35.0
LM5007MMX/NOPB	VSSOP	DGK	8	3500	367.0	367.0	35.0
LM5007SD/NOPB	WSON	NGT	8	1000	208.0	191.0	35.0
LM5007SDX/NOPB	WSON	NGT	8	4500	367.0	367.0	35.0

NGT0008A

PACKAGE OUTLINE

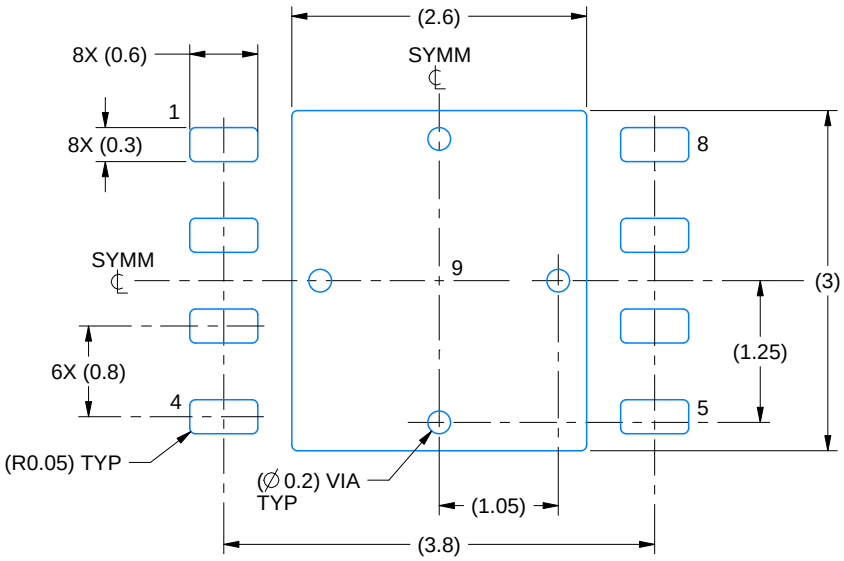
WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

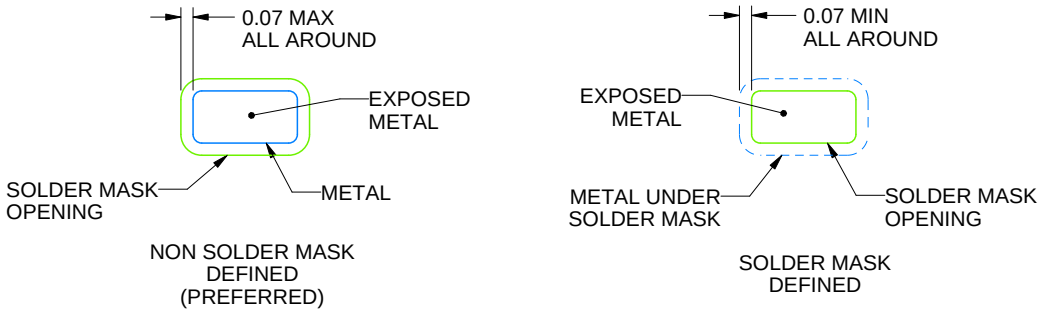


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

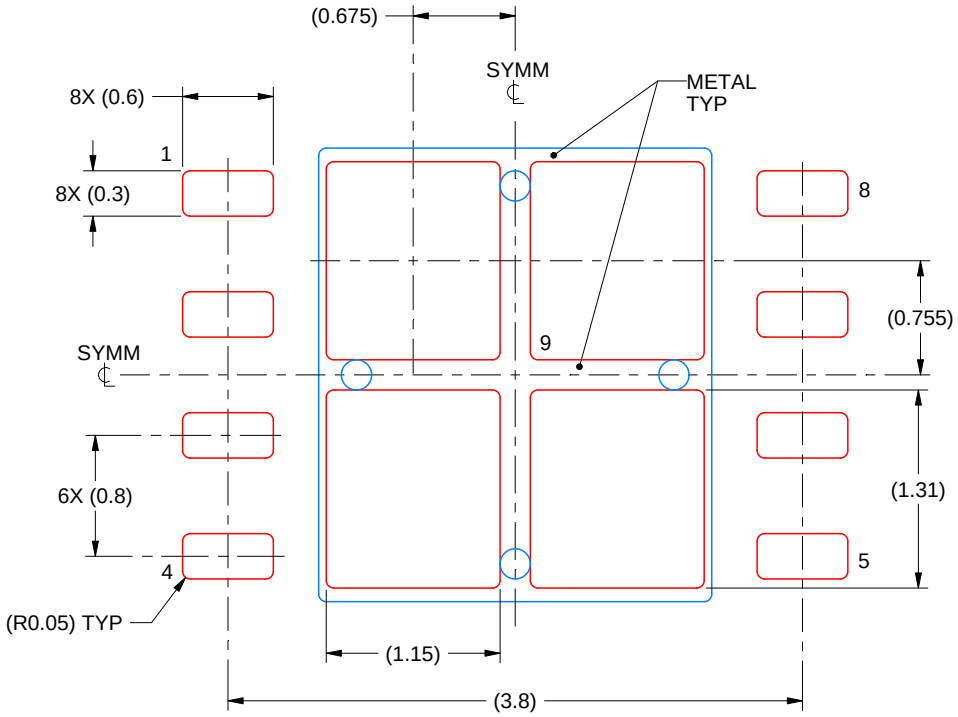


SOLDER MASK DETAILS

4214935/A 08/2020

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 9:
77% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:20X

4214935/A 08/2020

NOTES: (continued)

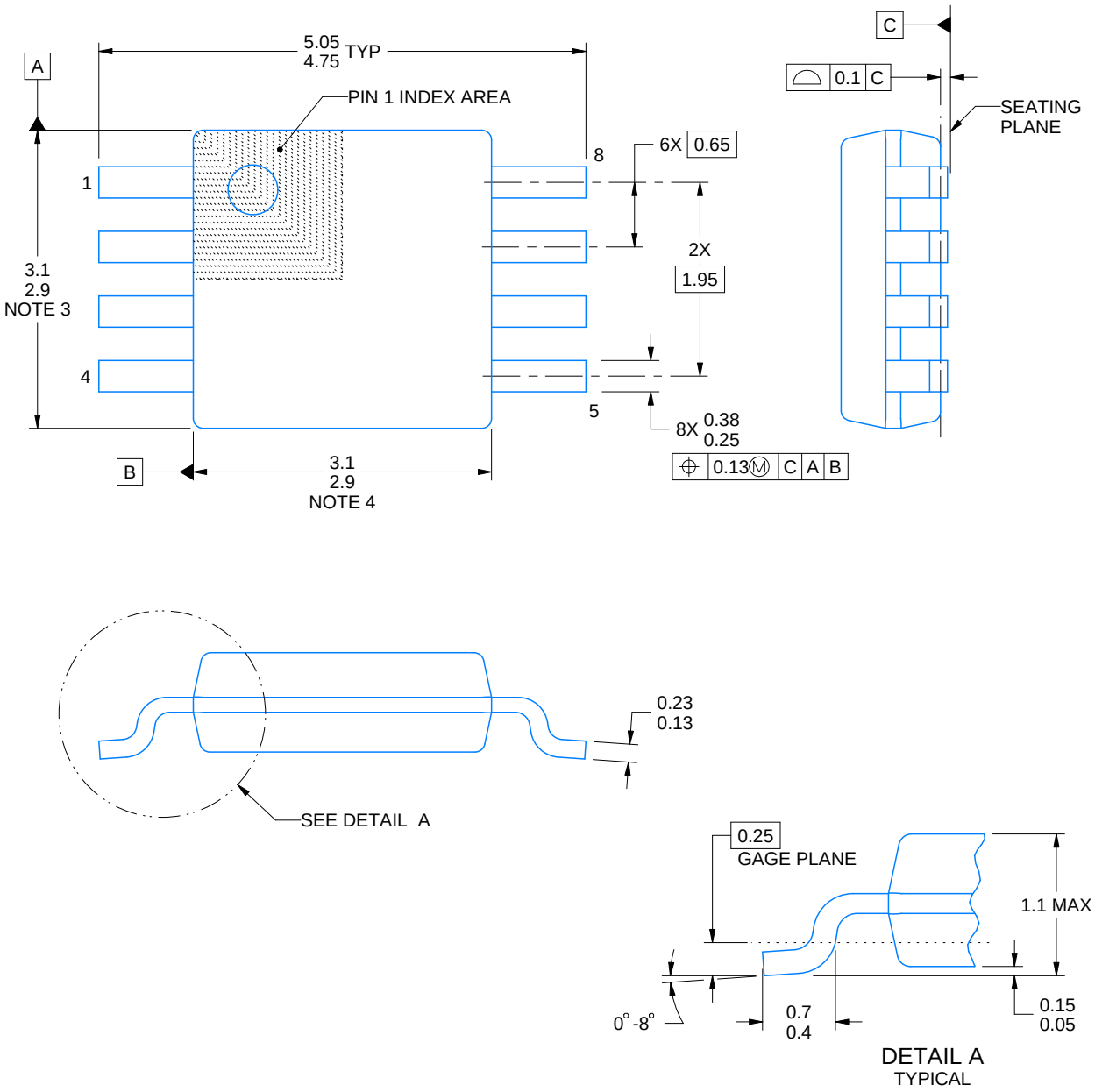
6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

PACKAGE OUTLINE

DGK0008A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



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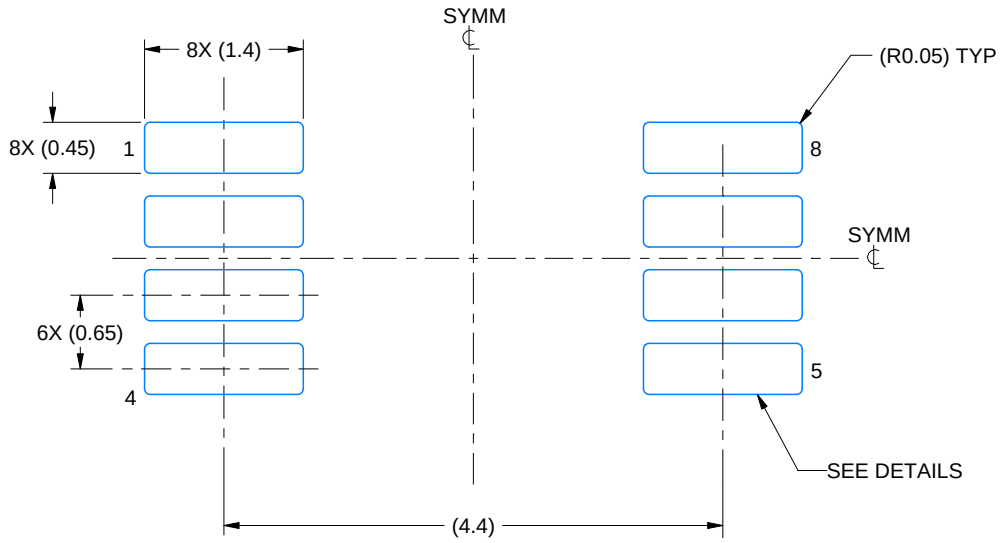
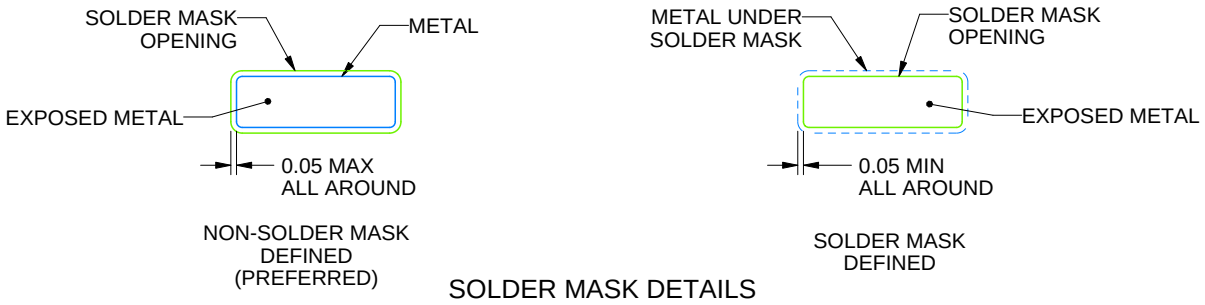
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X

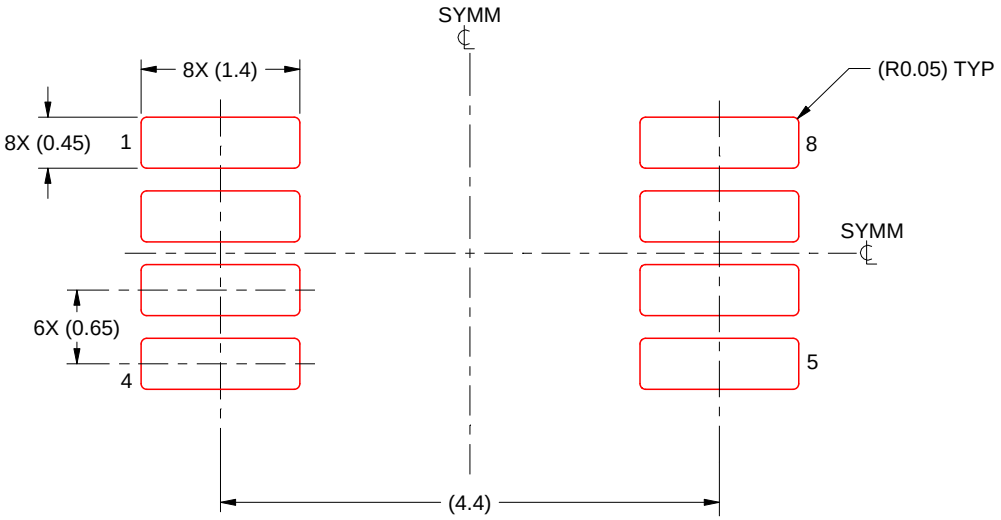


SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.



SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

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最終更新日：2025 年 10 月